

TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT    SILICON MONOLITHIC

# TC74HC4075AP, TC74HC4075AF

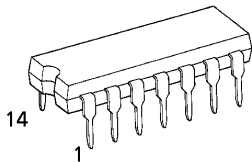
## TRIPLE 3-INPUT OR GATE

The TC74HC4075A is a high speed CMOS 3-INPUT OR GATE fabricated with silicon gate C<sup>2</sup>MOS technology. It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation. The internal circuit is composed of 4 stages including a buffered outputs, which provide high noise immunity and stable output.

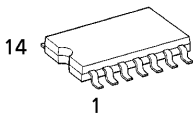
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

### FEATURES:

- High Speed..... $t_{pd} = 8\text{ns}(\text{typ.})$  at  $V_{CC} = 5\text{V}$
- Low Power Dissipation..... $I_{CC} = 2\mu\text{A}(\text{Max.})$  at  $T_a = 25^{\circ}\text{C}$
- High Noise Immunity..... $V_{NIH} = V_{NIL} = 28\% V_{CC} (\text{Min.})$
- Output Drive Capability ..... 10 LSTTL Loads
- Symmetrical Output Impedance...  $|I_{OH}| = I_{OL} = 4\text{mA}(\text{Min.})$
- Balanced Propagation Delays.....  $t_{pLH} \approx t_{pHL}$
- Wide Operating Voltage Range....  $V_{CC} (\text{opr.}) = 2\text{V} \sim 6\text{V}$
- Pin and Function Compatible with 4075B

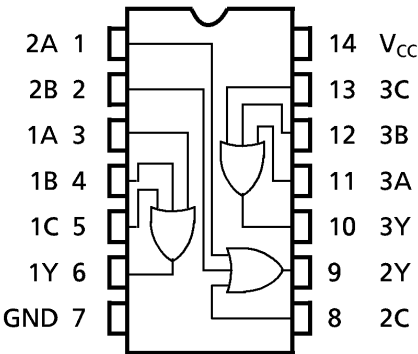


P (DIP14-P-300-2.54)  
Weight : 0.96g (Typ.)

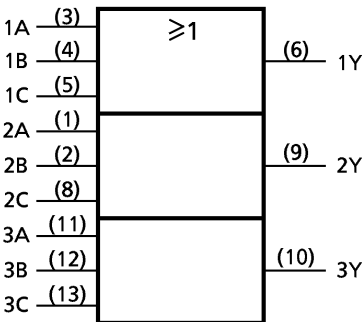


F (SOP14-P-300-1.27)  
Weight : 0.18g (Typ.)

### PIN ASSIGNMENT



### IEC LOGIC SYMBOL



### TRUTH TABLE

| A | B | C | Y |
|---|---|---|---|
| H | X | X | H |
| X | H | X | H |
| X | X | H | H |
| L | L | L | L |

X : Don't Care

## ABSOLUTE MAXIMUM RATINGS

| PARAMETER                   | SYMBOL    | VALUE                    | UNIT               |
|-----------------------------|-----------|--------------------------|--------------------|
| Supply Voltage Range        | $V_{CC}$  | $-0.5 \sim 7$            | V                  |
| DC Input Voltage            | $V_{IN}$  | $-0.5 \sim V_{CC} + 0.5$ | V                  |
| DC Output Voltage           | $V_{OUT}$ | $-0.5 \sim V_{CC} + 0.5$ | V                  |
| Input Diode Current         | $I_{IK}$  | $\pm 20$                 | mA                 |
| Output Diode Current        | $I_{OK}$  | $\pm 20$                 | mA                 |
| DC Output Current           | $I_{OUT}$ | $\pm 25$                 | mA                 |
| DC $V_{CC}$ /Ground Current | $I_{CC}$  | $\pm 50$                 | mA                 |
| Power Dissipation           | $P_D$     | 500 (DIP)* / 180 (SOP)   | mW                 |
| Storage Temperature         | $T_{stg}$ | $-65 \sim 150$           | $^{\circ}\text{C}$ |

\*500mW in the range of  $T_a = -40^{\circ}\text{C} \sim 65^{\circ}\text{C}$ . From  $T_a = 65^{\circ}\text{C}$  to  $85^{\circ}\text{C}$  a derating factor of  $-10\text{mW}/^{\circ}\text{C}$  shall be applied until 300mW.

## RECOMMENDED OPERATING CONDITIONS

| PARAMETER                | SYMBOL     | VALUE                                                                                                                          | UNIT               |
|--------------------------|------------|--------------------------------------------------------------------------------------------------------------------------------|--------------------|
| Supply Voltage           | $V_{CC}$   | $2 \sim 6$                                                                                                                     | V                  |
| Input Voltage            | $V_{IN}$   | $0 \sim V_{CC}$                                                                                                                | V                  |
| Output Voltage           | $V_{OUT}$  | $0 \sim V_{CC}$                                                                                                                | V                  |
| Operating Temperature    | $T_{opr}$  | $-40 \sim 85$                                                                                                                  | $^{\circ}\text{C}$ |
| Input Rise and Fall Time | $t_r, t_f$ | $0 \sim 1000$ ( $V_{CC} = 2.0\text{V}$ )<br>$0 \sim 500$ ( $V_{CC} = 4.5\text{V}$ )<br>$0 \sim 400$ ( $V_{CC} = 6.0\text{V}$ ) | ns                 |

## DC ELECTRICAL CHARACTERISTICS

| PARAMETER                      | SYMBOL   | TEST CONDITION                                         | $V_{CC}$<br>(V)           | $T_a = 25^{\circ}\text{C}$ |      |           | $T_a = -40 \sim 85^{\circ}\text{C}$ |           | UNIT          |
|--------------------------------|----------|--------------------------------------------------------|---------------------------|----------------------------|------|-----------|-------------------------------------|-----------|---------------|
|                                |          |                                                        |                           | MIN.                       | TYP. | MAX.      | MIN.                                | MAX.      |               |
| High - Level<br>Input Voltage  | $V_{IH}$ |                                                        | 2.0                       | 1.50                       | —    | —         | 1.50                                | —         | V             |
|                                |          |                                                        | 4.5                       | 3.15                       | —    | —         | 3.15                                | —         |               |
|                                |          |                                                        | 6.0                       | 4.20                       | —    | —         | 4.20                                | —         |               |
| Low - Level<br>Input Voltage   | $V_{IL}$ |                                                        | 2.0                       | —                          | —    | 0.50      | —                                   | 0.50      | V             |
|                                |          |                                                        | 4.5                       | —                          | —    | 1.35      | —                                   | 1.35      |               |
|                                |          |                                                        | 6.0                       | —                          | —    | 1.80      | —                                   | 1.80      |               |
| High - Level<br>Output Voltage | $V_{OH}$ | $V_{IN} = V_{IH} \text{ or } V_{IL}$                   | $I_{OH} = -20\mu\text{A}$ | 2.0                        | 1.9  | 2.0       | —                                   | 1.9       | V             |
|                                |          |                                                        | 4.5                       | 4.4                        | 4.5  | —         | 4.4                                 | —         |               |
|                                |          | $I_{OH} = -4 \text{ mA}$<br>$I_{OH} = -5.2 \text{ mA}$ | 4.5                       | 4.18                       | 4.31 | —         | 4.13                                | —         |               |
|                                |          |                                                        | 6.0                       | 5.68                       | 5.80 | —         | 5.63                                | —         |               |
| Low - Level<br>Output Voltage  | $V_{OL}$ | $V_{IN} = V_{IH} \text{ or } V_{IL}$                   | $I_{OL} = 20\mu\text{A}$  | 2.0                        | —    | 0.0       | —                                   | 0.1       | V             |
|                                |          |                                                        | 4.5                       | —                          | 0.0  | 0.1       | —                                   | 0.1       |               |
|                                |          | $I_{OL} = 4 \text{ mA}$<br>$I_{OL} = 5.2 \text{ mA}$   | 4.5                       | —                          | 0.17 | 0.26      | —                                   | 0.33      |               |
|                                |          |                                                        | 6.0                       | —                          | 0.18 | 0.26      | —                                   | 0.33      |               |
| Input Leakage Current          | $I_{IN}$ | $V_{IN} = V_{CC} \text{ or } \text{GND}$               | 6.0                       | —                          | —    | $\pm 0.1$ | —                                   | $\pm 1.0$ | $\mu\text{A}$ |
| Quiescent Supply Current       | $I_{CC}$ | $V_{IN} = V_{CC} \text{ or } \text{GND}$               | 6.0                       | —                          | —    | 1.0       | —                                   | 10.0      |               |

**AC ELECTRICAL CHARACTERISTICS (  $C_L = 15\text{pF}$ ,  $V_{CC} = 5\text{V}$ ,  $T_a = 25^\circ\text{C}$ , Input  $t_r = t_f = 6\text{ns}$  )**

| PARAMETER              | SYMBOL                 | TEST CONDITION | MIN. | TYP. | MAX. | UNIT |
|------------------------|------------------------|----------------|------|------|------|------|
| Output Transition Time | $t_{TLH}$<br>$t_{THL}$ |                | —    | 4    | 8    | ns   |
| Propagation Delay Time | $t_{PLH}$<br>$t_{PHL}$ |                | —    | 8    | 15   |      |

**AC ELECTRICAL CHARACTERISTICS (  $C_L = 50\text{pF}$ , Input  $t_r = t_f = 6\text{ns}$  )**

| PARAMETER                     | SYMBOL                               | TEST CONDITION | Ta = 25°C           |      |      |      | Ta = -40~85°C |      | UNIT |
|-------------------------------|--------------------------------------|----------------|---------------------|------|------|------|---------------|------|------|
|                               |                                      |                | V <sub>CC</sub> (V) | MIN. | TYP. | MAX. | MIN.          | MAX. |      |
| Output Transition Time        | t <sub>TLH</sub><br>t <sub>THL</sub> |                | 2.0                 | —    | 30   | 75   | —             | 95   | ns   |
|                               |                                      |                | 4.5                 | —    | 8    | 15   | —             | 19   |      |
|                               |                                      |                | 6.0                 | —    | 7    | 13   | —             | 16   |      |
| Propagation Delay Time        | t <sub>pLH</sub><br>t <sub>pHL</sub> |                | 2.0                 | —    | 35   | 90   | —             | 115  | ns   |
|                               |                                      |                | 4.5                 | —    | 11   | 18   | —             | 23   |      |
|                               |                                      |                | 6.0                 | —    | 9    | 15   | —             | 20   |      |
| Input Capacitance             | C <sub>IN</sub>                      |                |                     | —    | 5    | 10   | —             | 10   | pF   |
| Power Dissipation Capacitance | C <sub>PD</sub> (1)                  |                |                     | —    | 27   | —    | —             | —    |      |

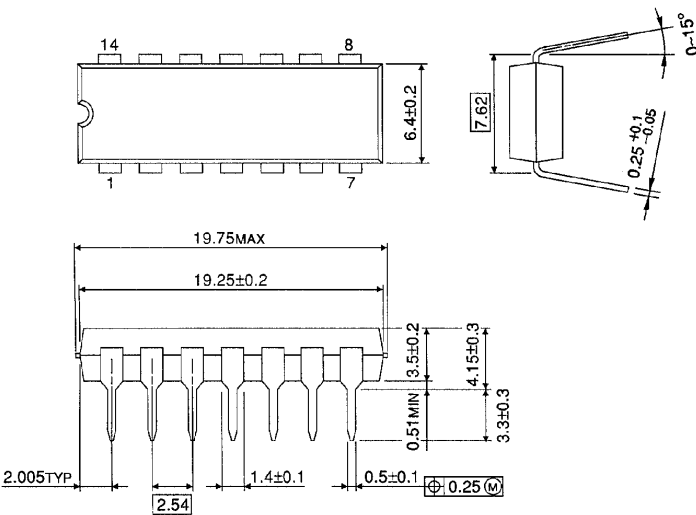
Note (1)  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation :

$$I_{CC}(\text{opr}) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 3 \text{ (per Gate)}$$

DIP 14PIN PACKAGE DIMENSIONS (DIP14-P-300-2.54)

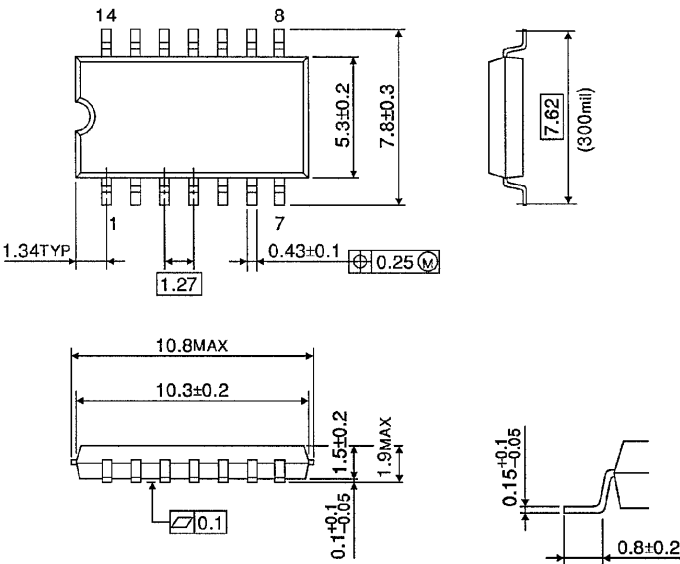
Unit in mm



Weight : 0.96g (Typ.)

SOP 14PIN (200mil BODY) PACKAGE DIMENSIONS (SOP14-P-300-1.27)

Unit in mm



Weight : 0.18g (Typ.)

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